

# CD54HC4024, CD74HC4024, CD54HCT4024

Data sheet acquired from Harris Semiconductor SCHS202C

November 1997 - Revised October 2003

# High-Speed CMOS Logic 7-Stage Binary Ripple Counter

#### Features

- · Fully Static Operation
- Buffered Inputs
- Common Reset
- Negative Edge Clocking
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility,  $V_{IL}$ = 0.8V (Max),  $V_{IH}$  = 2V (Min)
  - CMOS Input Compatibility,  $I_I \le 1\mu A$  at  $V_{OL}$ ,  $V_{OH}$

## Description

The 'HC4024 and 'HCT4024 are 7-stage ripple-carry binary counters. All counter stages are master-slave flip-flops. The state of the stage advances one count on the negative transition of each input pulse; a high voltage level on the MR line resets all counters to their zero state. All inputs and outputs are buffered.

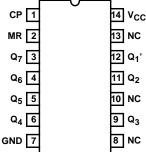
## **Ordering Information**

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4024F3A	-55 to 125	14 Ld CERDIP
CD54HCT4024F3A	-55 to 125	14 Ld CERDIP
CD74HC4024E	-55 to 125	14 Ld PDIP
CD74HC4024M	-55 to 125	14 Ld SOIC
CD74HC4024MT	-55 to 125	14 Ld SOIC
CD74HC4024M96	-55 to 125	14 Ld SOIC
CD74HC4024PW	-55 to 125	14 Ld TSSOP
CD74HC4024PWR	-55 to 125	14 Ld TSSOP
CD74HC4024PWT	-55 to 125	14 Ld TSSOP
CD74HCT4024E	-55 to 125	14 Ld PDIP
CD74HCT4024M	-55 to 125	14 Ld SOIC

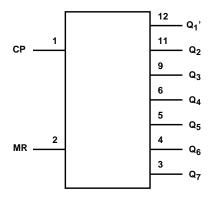
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

#### **Pinout**

CD54HC4024, CD54HCT4024
(CERDIP)
CD74HC4024
(PDIP, SOIC, TSSOP)
CD74HCT4024
(PDIP, SOIC)
TOP VIEW



# Functional Diagram

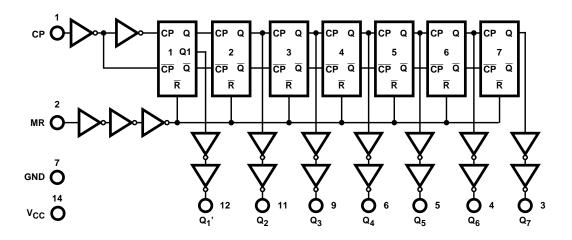


## TRUTH TABLE

CP COUNT	MR	OUTPUT STATE
1	L	No Change
<b>\</b>	L	Advance to Next State
Х	Н	All Outputs Are Low

H = High Voltage Level, L = Low Voltage Level, X = Don't Care,

# Logic Diagram



 $<sup>\</sup>uparrow$  = Transition from Low to High Level,  $\downarrow$  = Transition from High to Low.

## 

#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	θ <sub>JA</sub> (ºC/W)
E (PDIP) Package	. 80
M (SOIC) Package	. 86
PW (TSSOP) Package	. 113
(Maximum Junction Temperature	
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300 <sup>o</sup> C
(SOIC - Lead Tips Only)	

## **Operating Conditions**

Temperature Range (T <sub>A</sub> )55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

		TEST CONDITIONS		V <sub>CC</sub>		25°C			-40°C TO 85°C		-55°C TO 125°C							
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS						
HC TYPES																		
High Level Input V <sub>IH</sub> Voltage	-	-	2	1.5	-	-	1.5	-	1.5	-	V							
				4.5	3.15	-	-	3.15	-	3.15	-	V						
				6	4.2	-	-	4.2	-	4.2	-	V						
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V						
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V						
				6	-	-	1.8	-	1.8	-	1.8	V						
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	V						
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V						
omeo zoado			-0.02	6	5.9	-	-	5.9	-	5.9	-	V						
High Level Output	7		-	-	-	-	-	-	-	-	-	V						
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V						
112 20000			-5.2	6	5.48	-	-	5.34	-	5.2	-	V						
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	V						
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V						
OWIGO Educa			0.02	6	-	-	0.1	-	0.1	-	0.1	V						
Low Level Output	7						t		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V						
TTE Education			5.2	6	-	-	0.26	-	0.33	-	0.4	V						
Input Leakage Current	lį	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ						
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μΑ						

# DC Electrical Specifications (Continued)

		TE: CONDI	_			-40°C 1	O 85°C	-55°C TO 125°C					
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HCT TYPES													
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V	
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V	
High Level Output Voltage CMOS Loads	Voн	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V	
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	lį	V <sub>CC</sub> and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ	
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μΑ	
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ	

## NOTE:

# **HCT Input Loading Table**

INPUT	UNIT LOADS
CP, MR	0.5

NOTE: Unit Load is  $\Delta l_{CC}$  limit specified in DC Electrical Table, e.g., 360µA max at 25  $^{\rm o}C$ .

# **Prerequisite for Switching Specifications**

			25	o <sub>C</sub>	-40°C 1	TO 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-			-					-
Maximum Input Pulse Frequency	f <sub>MAX</sub>	2	6	-	5	-	4	-	MHz
		4.5	30	-	24	-	20	-	MHz
		6	35	-	29	-	24	-	MHz
Input Pulse Width	t <sub>W</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Reset Removal Time	t <sub>REM</sub>	2	50	-	65	-	75	-	ns
		4.5	10	-	13	-	15	-	ns
		6	9	-	11	-	13	-	ns

<sup>2.</sup> For dual-supply systems theoretical worst case ( $V_I = 2.4V$ ,  $V_{CC} = 5.5V$ ) specification is 1.8mA.

# Prerequisite for Switching Specifications (Continued)

			25°C		-40°C T	O 85°C	-55°C T		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Reset Pulse Width	t <sub>W</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
HCT TYPES									
Maximum Input Pulse Frequency	f <sub>MAX</sub>	4.5	25	-	20	-	16	-	MHz
Input Pulse Width	t <sub>W</sub>	4.5	20	-	25	-	30	-	ns
Reset Recovery Time	t <sub>REC</sub>	4.5	10	-	13	-	15	-	ns
Reset Pulse Width	t <sub>W</sub>	4.5	20	-	25	-	30	-	ns

# Switching Specifications Input $t_{r}$ , $t_{f} = 6 \text{ns}$

		TEST	Vcc		25°C		-40°C 1	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	•			•		•					
Propagation Delay Time (Figure 1)	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	2	-	-	140	-	175	-	210	ns
CP to Q1' Output			4.5	-	-	28	-	35	-	42	ns
		C <sub>L</sub> =15pF	5	-	11	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	24	-	30	-	36	ns
Q <sub>n</sub> to Q <sub>n</sub> + 1	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
	t <sub>PHL</sub>		4.5	-	-	15	-	19	-	22	ns
		C <sub>L</sub> =15pF	5	-	6	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	13	-	13	-	19	ns
MR to Q <sub>n</sub>	t <sub>PLH,</sub> t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	170	-	215	-	255	ns
			4.5	-	-	34	-	43	-	51	ns
			5	-	14	-	-	-	-	-	ns
			6	-	-	29	-	27	-	43	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> =15pF	5	-	30	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay Time (Figure 2)	t <sub>PLH,</sub> t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	40	-	50	-	60	ns
CP to Q1' Output		C <sub>L</sub> =15pF	5	-	17	-	-	-	-	-	ns
Q <sub>n</sub> to Q <sub>n</sub> + 1	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
	<sup>t</sup> PHL	C <sub>L</sub> =15pF	5	-	6	-	-	-	-	-	ns
MR to Q <sub>n</sub>	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	4.5	-	-	40	-	50	-	60	ns
	tPHL	C <sub>L</sub> =15pF	5	-	17	-	-	-	-	-	ns

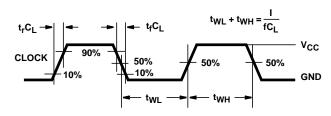
## Switching Specifications Input $t_r$ , $t_f = 6ns$ (Continued)

		TEST V <sub>CC</sub>		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Transition	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> =15pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> =15pF	5	-	30	-	-	-	-	-	pF

#### NOTES:

- 3. CPD is used to determine the dynamic power consumption, per package.
- 4.  $P_D = V_{CC}^2 f_i + \sum (C_L V_{CC}^2 f_i/M)$  where:  $M = 2^1$ ,  $2^2$ ,  $2^3$ ,  $2^4$ ,  $2^5$ ,  $2^6$ ,  $2^7 f_i = Input Frequency, <math>C_L = Output Load Capacitance$ ,  $V_{CC} = Supply Voltage$ .

## Test Circuits and Waveforms



NOTE: Outputs should be switching from 10%  $V_{CC}$  to 90%  $V_{CC}$  in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

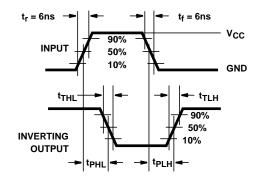
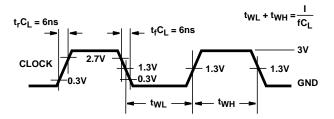


FIGURE 3. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC



NOTE: Outputs should be switching from 10%  $V_{CC}$  to 90%  $V_{CC}$  in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

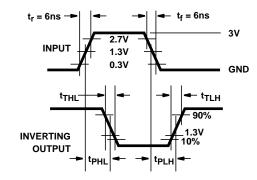


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



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## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD54HC4024F	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type
CD54HCT4024F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type
CD74HC4024E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC4024EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC4024M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWTE4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4024PWTG4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT4024E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT4024EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT4024M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT4024ME4	ACTIVE	SOIC	D	14	50	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM



#### PACKAGE OPTION ADDENDUM

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Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
					no Sb/Br)		
CD74HCT4024MG4	ACTIVE	SOIC	D	14 50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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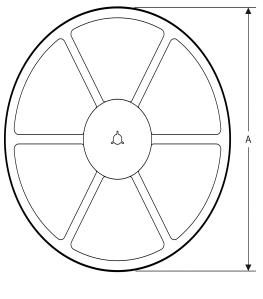
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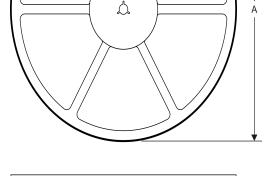
# PACKAGE MATERIALS INFORMATION

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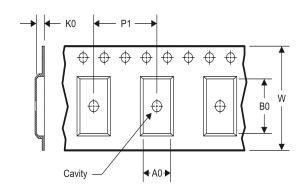
## TAPE AND REEL INFORMATION

## **REEL DIMENSIONS**





## **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## TAPE AND REEL INFORMATION

## \*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4024M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC4024MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC4024PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4024PWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4024M96	SOIC	D	14	2500	367.0	367.0	38.0
CD74HC4024MT	SOIC	D	14	250	367.0	367.0	38.0
CD74HC4024PWR	TSSOP	PW	14	2000	367.0	367.0	35.0
CD74HC4024PWT	TSSOP	PW	14	250	367.0	367.0	35.0

## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE

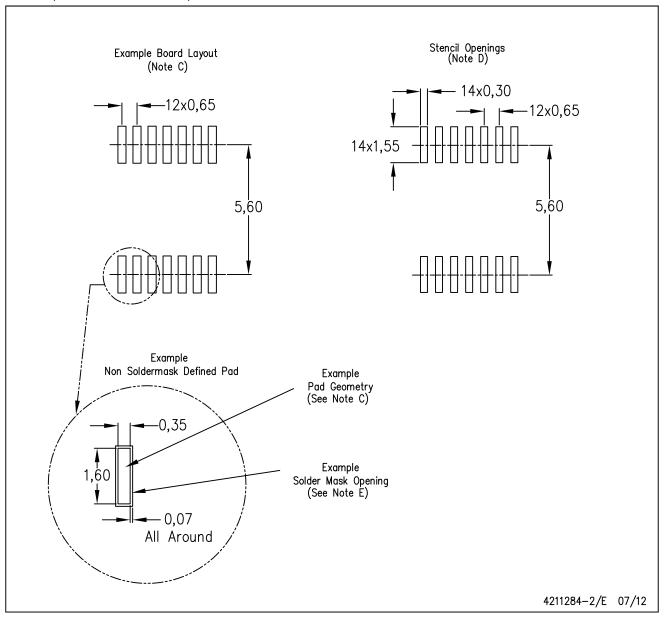


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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